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Application Note

LOW-CURRENT SILICON MMIC AMPLIFIERS FOR CELLULAR/CORDLESS TELEPHONES

USAGE AND APPLICATIONS OF μ PC8128TB, μ PC8151TB, AND μ PC8152TB

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Date Published March 1999 N CP (K)

[MEMO]

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| (1) | Obs Forr | erve pre n a grou | r design-ins ecautions for handling because of electro-static sensitive devices. and pattern as widely as possible to minimize ground impedance (to prevent undesing pins must be connected together with wide ground pattern to decrease impedance | • |

(3) The bypass capacitor should be attached to Vcc line.

INTRODUCTION

- (4) The inductor (L) should be attached between Vcc pin and output pin. The L and series capacitor (C2) values should be adjusted for applied frequency to match impedance to next stage.
- (5) The DC cut capacitor must be attached to input pin.
- (6) You should apply voltage to Vcc pin and output pin. You must not apply voltage to input pin nor regulate input pin voltage (e.g. direct DC pull-down).

1. INTRODUCTION

The market for mobile terminals has been expanding continuously in recent years, and as the market share of hand-held unit advances, there is a growing demand for terminals that are more compact and consume less power. In addition, recent trends concerning hand-held unit demand that the integrated circuits (ICs) used in this equipment also must become more compact and consume less power.

NEC has been selling the μ PC2714, μ PC2715, and μ PC2745 to μ PC2748 products as local buffer ICs for mobile communication systems for some time now. However, to satisfy the demands for compact size, low power consumption, and high isolation, NEC has developed and created the μ PC8128TB, μ PC8151TB, and μ PC8152TB low-current silicon microwave monolithic IC (MMIC) amplifiers to be used as various types of buffers for mobile communication systems.

These application notes introduce the features and application characteristics of these products.

See the data sheet for each product for details of the product's ratings, specifications, and usable conditions.

2. PRODUCT LINE-UP

2.1 Characteristics

Table 2-1 shows the line-up of low-current silicon MMIC amplifiers for cellular/cordless telephones.

Table 2-1. Low-Current Silicon MMIC Amplifiers for Cellular/Cordless Telephones Product Line-up $(T_A = +25^{\circ}C, V_{CC} = V_{out} = 3.0 \text{ V}, Z_L = Z_S = 50 \Omega)$

| Part Number | Vcc | Icc | | Hz Outpuning Frequen | | | GHz Outpo | | | Hz Outpu | | NA - oldo - |
|--------------------|--------|------|------------------------|----------------------|-----------------|------------------------|-------------|-----------------|------------------------|-------------|-----------------|-------------|
| (Bulk Part Number) | (V) | (mA) | G _P (dB) | ISL (dB) | Po (1 dB) (dBm) | G _P (dB) | ISL (dB) | Po (1 dB) (dBm) | G _P (dB) | ISL (dB) | Po (1 dB) (dBm) | Marking |
| μPC8128TB | 2.4 to | 2.8 | 12.5 | 39 | -4.0 | 13.0 | 39 | -4.0 | 13.0 | 37 | -4.0 | C2P |
| μPC8151TB | 3.3 | 4.2 | 12.5 | 38 | +2.5 | 15.0 | 36 | +1.5 | 15.0 | 34 | +0.5 | C2U |
| μPC8152TB | | 5.6 | 23.0 | 40 | -4.5 | 19.5 | 36 | -8.5 | 17.5 | 35 | -8.5 | C2V |

Remark The above values are typical values for major characteristics. See each product's data sheet for detailed ratings and characteristic, etc.

This line-up achieves low-current consumption, high efficiency, and high gain with the power supply voltage in the 3-V range. The low circuit current consumption is approximately 40% of the 5 to 7.5 mA consumed by the existing μ PC2745 to μ PC2748 products. These products use a 6-pin mini mold package of size 2012. Figure 2-1 shows external views of this package (package drawing).

Due to limited printing space on these mini mold ICs, a three-character is marked instead of part number shown on the molds. Each three-character marking corresponds to a different part number. Due to space limitations, the pin 1 mark is printed on the bottom side. Figure 2-2 shows a marking example of these products.

Taping is used as the supplying form for all products and the part number is "Bulk part No. - taping code." For details, refer to the data sheet.

All ICs in this product line-up have been developed and manufactured using NEC's proprietary NESAT™ III silicon bipolar process. For details about this process, refer to the pamphlet entitled "NESAT Process pamphlet" (Document No. P12647E).

Figure 2-1. Package Drawing of 6-Pin Super Mini-Mold Low-Current Silicon MMIC Amplifiers

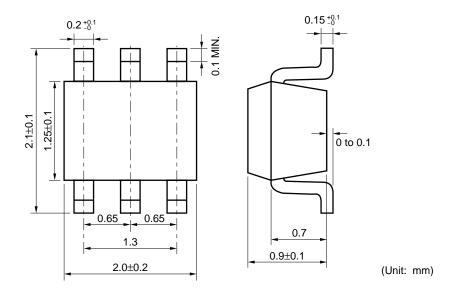
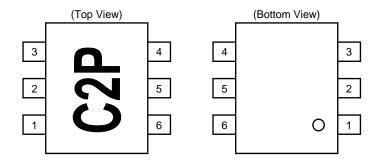


Figure 2-2. Exterior of the Marking Example



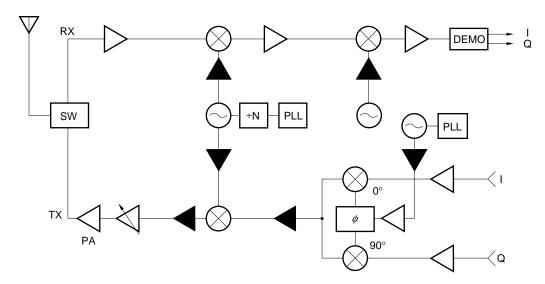
Remark The marking example shown in the above figure corresponds to μ PC8128TB.

2.2 System Application Example

Figure 2-3 shows a system block diagram that can be considered as an application example of these ICs due to system requirement characteristics.

Figure 2-3. System Block Diagram

Location examples in digital cellular



These ICs can be added to your system around \blacktriangle parts, when you need more isolation or gain. The application herein, however, shows only examples, therefore the application can depend on your kit evaluation.

3. THEORETICAL DESCRIPTION

3.1 Description of Internal Circuits

The μ PC8128TB and μ PC8151TB have simple two-stage configurations without negative feedback. The μ PC8152TB incorporates 50- Ω matching circuit formed by resistors on the input side. A multiple negative feedback circuit is provided to offset the variations between HFE and resistance. To obtain desired RF characteristics, a two-stage configuration is employed. Figure 3-1 shows an internal equivalent circuit.

The output pins of the ICs in this product line-up are used to constitute matching circuits externally, and low current consumption is achieved due to open collector output of the output-stage transistor and by high impedance output. For the bias to the output pins, the same voltage as the Vcc is applied via the inductor of the matching circuit.

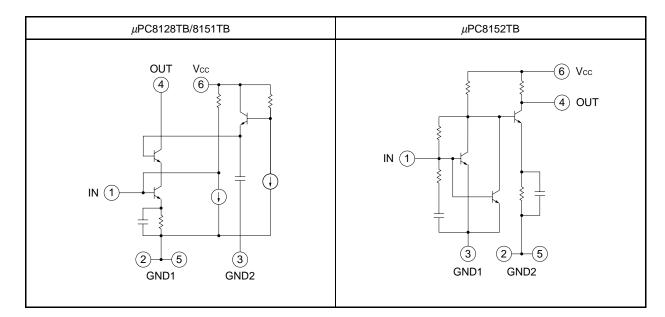


Figure 3-1. Internal Equivalent Circuits of Low-Current Silicon MMIC Amplifiers

3.2 Description of External Circuits

External Circuit Configuration

By attaching an external inductor to the output pin, the ICs in this product line-up can achieve low-current consumption that could not be obtained by conventional internal 50- Ω wideband matching ICs. Therefore, a narrowband matching circuit should be configured by using an LC externally attached to the output pin to suit the usage frequency. Also, since the μ PC8128TB or μ PC8151TB does not have an on-chip 50- Ω matching circuit based on the resistance of the IC's input stage, the input stage return loss increases. To improve the input stage return loss of the μ PC8128TB or μ PC8151TB, a narrowband matching circuit that suits the usage frequency is also required at the input stage.

The following three external circuit configurations can be considered according to the differences of the matching circuits.

- <1> Output isolation matching (no matching for the input stage, and an output stage return loss optimized to approximately 10 to 20 dB)
- <2> Output 50- Ω matching (no matching for the input stage, and matching of the output stage to 50 Ω)
- <3> Input/output 50- Ω matching (matching both of the input and output stages to 50 Ω)

Design Method

For <2> and <3> above, the $50-\Omega$ matching circuit of the LC should be designed based on the S parameter of the IC while also taking into account mounting circuit board elements. However, for <1>, since definite points cannot be represented on a Smith chart, the following procedure must be used to adjust the values.

- First, match the output stage to 50 Ω for a standard.
- Next, while using a network analyzer to monitor S12, adjust the mounting position and constants of the externally attached circuit (LC) so that the isolation can be excellent.

At NEC, excellent isolation was obtained when this procedure was used to adjust the output stage return loss to the range of 10 to 20 dB.

The circuit constants that appear in these application notes and the data sheets are values for the corresponding evaluation boards. Since the evaluation boards, which are designed for simple evaluation, occupy considerable space, they cannot be applied directly in an actual system. The S parameter values (MAG and ANG) and input/output Smith charts of the ICs themselves are included in the data sheets and in the appendix of this document for reference by users of matching circuit design. Users should optimize the matching circuit constants by referring to this explanation and carefully considering these parameters and the mounting circuit board elements.

The characteristic curves that appear in the data sheets were measured by creating a matching circuit that emphasizes isolation (<1> Isolation matching). For characteristics in the circuit configurations of <2> and <3>, see Table 4-1 Measurement Results in 4.1 Application Characteristics for Various Matching Methods.

3.3 Test Circuit

To measure the electrical specifications described in the data sheet, a test circuit was used in which a matching circuit was created by an LC at the output pin. Figure 3-2 shows the test circuit used for these ICs, and Figure 3-3 shows the evaluation board layout.

Figure 3-2. Test Circuit

This test circuit is used in an NEC measurement jig. Multiple bypass capacitors are used in the Vcc line due to the board pattern design of the NEC jig. The number of bypass capacitors should be reduced by optimizing the circuit board pattern when performing an actual application.

Figure 3-3. Evaluation Board for μ PC8128TB, μ PC8151TB, and μ PC8152TB

Notes regarding board examples

- Board material ----- Double-sided copper clad polyamide board is used to reduce loss due to the board.
- Back side -----Entire side is ground pattern. Through holes are used to ensure proper grounding for IC mounting side.
- Specifications------ Board dimensions: $42 \times 35 \times 0.4$ mm, with 35- μ m thick copper patterning on both sides.

4. SAMPLE APPLICATION CHARACTERISTICS

4.1 Application Characteristics for Various Matching Methods

The ICs in this line-up were turned in a narrow band to a usage frequency within the recommended operating frequency range (100 to 1900 MHz). This section introduces the results of evaluating the characteristics for each matching method.

These evaluations where performed according to each of the three matching methods, namely output isolation matching (matching for which isolation is best), output $50-\Omega$ matching, and input/output $50-\Omega$ matching, at frequencies of 1.0, 1.66, and 1.9 GHz, using the μ PC8128TB. Table 4-1 shows the evaluation results and Figure 4-1 shows the measurement circuits.

The isolation and noise figure values were better for the output isolation matching method than for the other matching methods. Since the output return loss and input return loss are improved for the output $50-\Omega$ matching and input/output $50-\Omega$ matching methods, the power gain becomes 1 to 2 dB higher than for the output isolation matching method. However, the isolation and noise figure results were worse. These evaluation results indicate that when isolation and noise figure characteristics are emphasized, the output isolation matching method is optimum, but when power gain is emphasized even if the isolation and noise figure are made somewhat worse, the methods that match the output and input stages to $50~\Omega$ are optimum. The points at which isolation was best in these evaluation results (output isolation matching) were obtained by setting the output return loss in the 10 to 20 dB range.

These evaluations were also performed for the μ PC8151TB using the same internal circuits as were used for the μ PC8128TB, and similar results were obtained.

Table 4-1. Measurement Results

Test Conditions: TA = +25°C, Vcc = Vout = 3.0 V, ZL = ZS = 50 Ω

1.0-GHz Tuning

| 10 O.1.2 1 d.1.1.1.9 | | | | | | |
|--------------------------|-------------------------------|--------------------------------|------------------------|-----------------------|-------------------------|--|
| Matching Method | Input Return Loss S11 (dB) | Output Return Loss S22 (dB) | Power Gain S21 (dB) | Isolation S12 (dB) | Noise Figure NF (dB) | |
| Output isolation | 4.6 | 15.3 | 11.7 | 37.3 | 5.9 | |
| Output 50 Ω | 4.6 | 35.1 | 12.0 | 36.7 | 6.0 | |
| Input/output 50 Ω | 30.7 | 27.3 | 13.6 | 34.9 | 6.6 | |

1.66-GHz Tuning

| Matching Method | Input Return Loss S11 (dB) | Output Return Loss S22 (dB) | Power Gain S21 (dB) | Isolation S12 (dB) | Noise Figure NF (dB) |
|-------------------|-------------------------------|--------------------------------|------------------------|-----------------------|-------------------------|
| Output isolation | 5.8 | 16.6 | 11.0 | 41.2 | 5.9 |
| Output 50 Ω | 6.3 | 26.5 | 11.0 | 37.8 | 6.0 |
| Input/output 50 Ω | 30.8 | 27.6 | 12.1 | 35.2 | 6.7 |

1.9-GHz Tuning

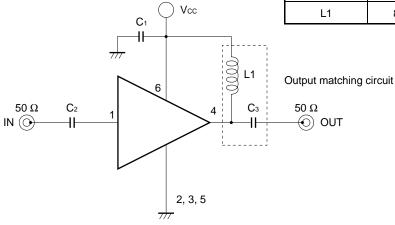
| · · · · · · · · · · · · · · · · · · · | | | | | |
|---------------------------------------|-------------------------------|--------------------------------|------------------------|-----------------------|-------------------------|
| Matching Method | Input Return Loss S11 (dB) | Output Return Loss S22 (dB) | Power Gain S21 (dB) | Isolation S12 (dB) | Noise Figure NF (dB) |
| Output isolation | 6.0 | 11.6 | 11.1 | 38.3 | 5.9 |
| Output 50 Ω | 6.3 | 33.1 | 11.9 | 36.2 | 6.0 |
| Input/output 50 Ω | 31.7 | 29.8 | 12.0 | 35.5 | 7.0 |

Figure 4-1. Test Circuits

(1) Output isolation matching circuit

Component List

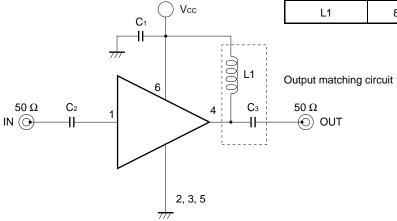
| | 1.0-GHz Tuning | 1.66-GHz Tuning | 1.9-GHz Tuning |
|---------------------------------|----------------|-----------------|----------------|
| C ₁ , C ₂ | 1 000 pF | 1 000 pF | 1 000 pF |
| Сз | 1.0 pF | 0.7 pF | 0.5 pF |
| L1 | 8.2 nH | 3.3 nH | 1.8 nH |



(2) Output 50- Ω matching circuit

Component List

| Component List | | | | | | | |
|---------------------------------|----------------|-----------------|----------------|--|--|--|--|
| | 1.0-GHz Tuning | 1.66-GHz Tuning | 1.9-GHz Tuning | | | | |
| C ₁ , C ₂ | 1 000 pF | 1 000 pF | 1 000 pF | | | | |
| Сз | 0.8 pF | 0.7 pF | 0.6 pF | | | | |
| L1 | 8.2 nH | 3.3 nH | 1.7 nH | | | | |



Notes: Used parts for this evaluations

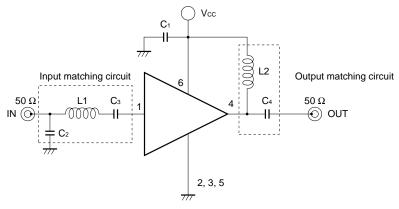
C: Murata's size 1608 chip capacitor

L: TOKO's LL2012 Multilayer chip inductor

(3) Input/output 50- Ω matching circuit

Component List

| Component List | | | | | | |
|----------------|----------------|-----------------|----------------|--|--|--|
| | 1.0-GHz Tuning | 1.66-GHz Tuning | 1.9-GHz Tuning | | | |
| C ₁ | 1 000 pF | 1 000 pF | 1 000 pF | | | |
| C2 | 1.0 pF | 1.5 pF | 1.5 pF | | | |
| Сз | 1 000 pF | 1 000 pF | 1 000 pF | | | |
| C4 | 0.8 pF | 0.7 pF | 0.6 pF | | | |
| L1 | 10 nH | 1.5 nH | 2.7 nH | | | |
| L2 | 8.2 nH | 3.3 nH | 1.7 nH | | | |



4.2 Characteristics for IF Band Tuning

Although the ICs in this line-up were developed as various types of buffer amplifiers for cellular or cordless telephones, the recommended operating frequency range is 100 to 1900 MHz, and these ICs can also be used at IF-band frequencies. For this section, the characteristics were measured for input/output tunings at operating frequencies of 130 MHz and 240MHz, which are used frequently in the IF band. Table 4-2 shows the measurement results, and Figure 4-2 shows the measurement circuits. When these ICs were used in the IF band, the power gain was higher and the isolation was better than when they were used in the 1 to 2 GHz range.

Table 4-2. Measurement Results

Test Conditions: TA = +25°C, Vcc = Vout = 3.0 V, ZL = Zs = 50 Ω

130-MHz Input/Output Tuning (Output Tuning Only for the μPC8152TB)

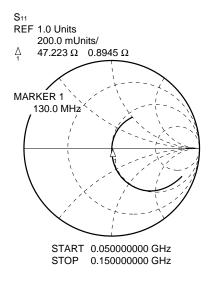
| g (a mpan a man g) a mpan a man g a m g a m g a m g a m g a m g a m g a m g a m g a m g a m g a m g a m g a m | | | | | | |
|---|-------------------------------|--------------------------------|------------------------|-----------------------|-------------------------|--|
| Part No. | Input Return Loss S11 (dB) | Output Return Loss S22 (dB) | Power Gain S21 (dB) | Isolation S12 (dB) | Noise Figure NF (dB) | |
| μPC8128TB | 30.8 | 10.2 | 17.9 | 41.5 | 6.1 | |
| μPC8151TB | 29.4 | 11.6 | 18.7 | 42.5 | 6.3 | |
| μPC8152TB | 26.7 | 18.8 | 19.7 | 51.8 | 3.1 | |

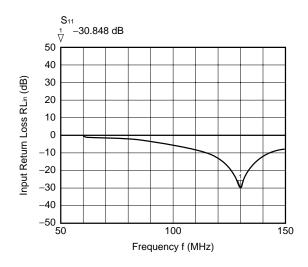
240-MHz Input/Output Tuning (Output Tuning Only for the μPC8152TB)

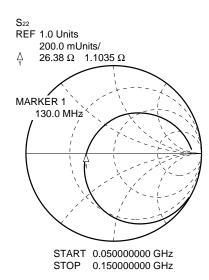
| Part No. | Input Return Loss S11 (dB) | Output Return Loss S22 (dB) | Power Gain S21 (dB) | Isolation S12 (dB) | Noise Figure NF (dB) |
|-----------|-------------------------------|--------------------------------|------------------------|-----------------------|-------------------------|
| μPC8128TB | 37.9 | 32.3 | 16.9 | 36.1 | 6.2 |
| μPC8151TB | 22.3 | 29.3 | 16.4 | 37.3 | 6.5 |
| μPC8152TB | 25.5 | 21.8 | 20.2 | 48.2 | 3.2 |

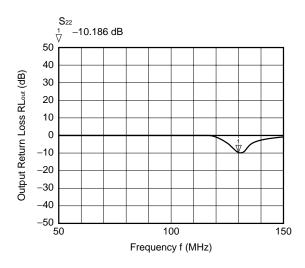
4.2.1 μPC8128TB Characteristics for 130-MHz Tuning

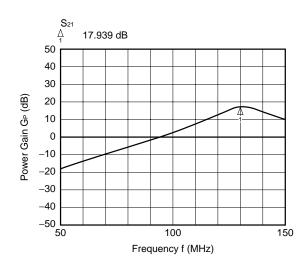
Conditions: TA = +25°C, Vcc = Vout = 3.0 V, ZL = Zs = 50 Ω

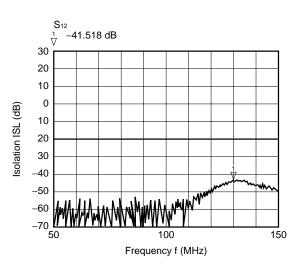




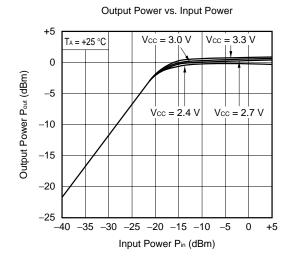


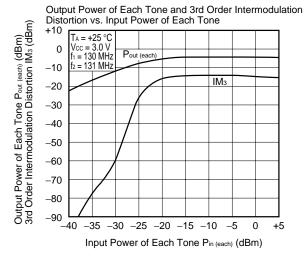


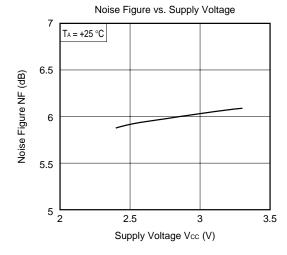




μ PC8128TB Characteristics for 130-MHz Tuning

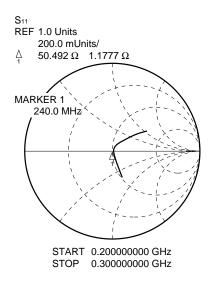


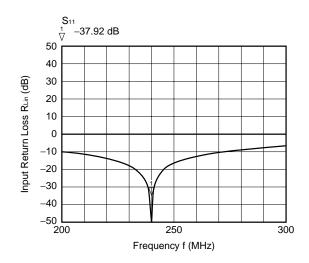


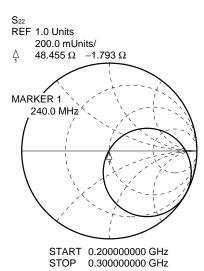


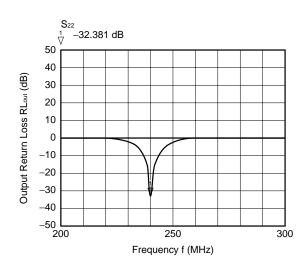
4.2.2 μPC8128TB Characteristics for 240-MHz Tuning

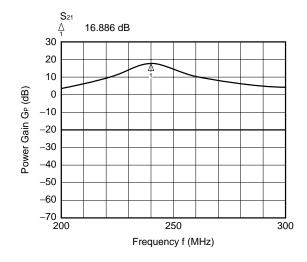
Conditions: TA = +25°C, Vcc = Vout = 3.0 V, ZL = Zs = 50 Ω

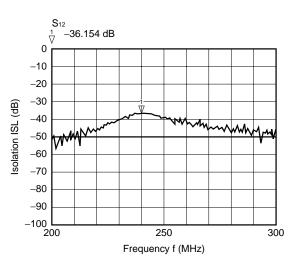




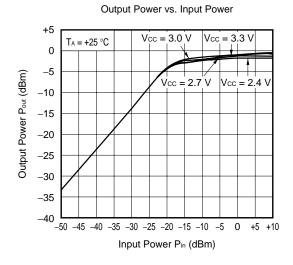


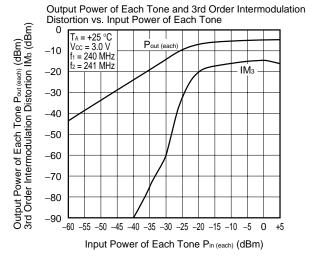


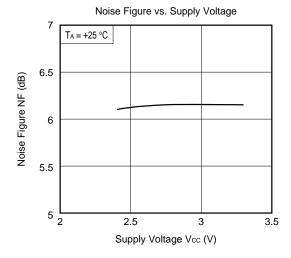




μ PC8128TB Characteristics for 240-MHz Tuning

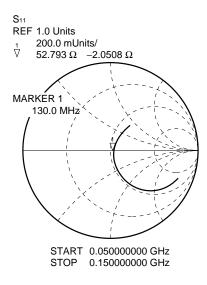


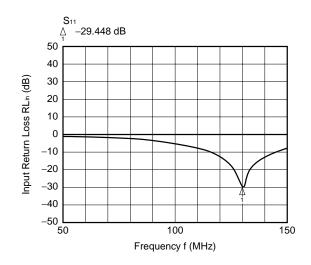


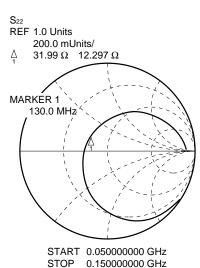


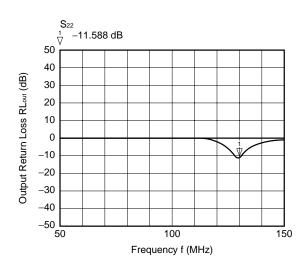
4.2.3 μPC8151TB Characteristics for 130-MHz Tuning

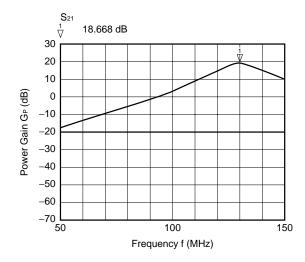
Conditions: T_A = +25°C, V_{CC} = V_{out} = 3.0 V, Z_L = Z_S = 50 Ω

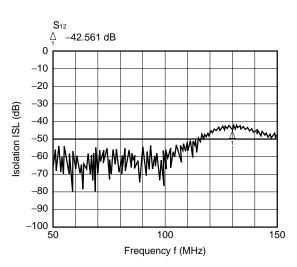




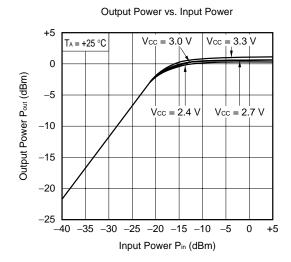


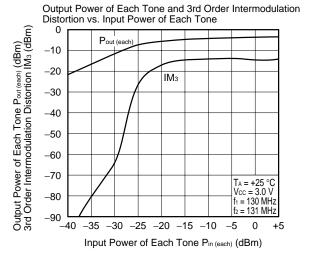


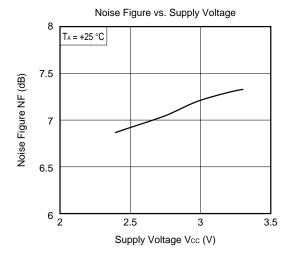




μ PC8151TB Characteristics for 130-MHz Tuning

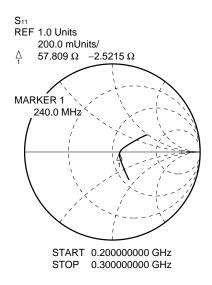


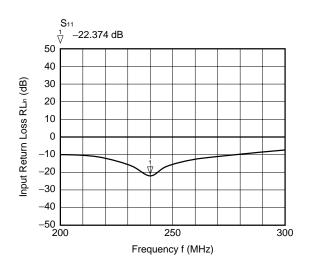


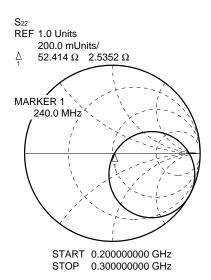


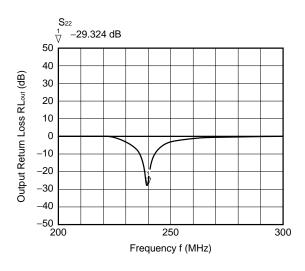
4.2.4 μPC8151TB Characteristics for 240-MHz Tuning

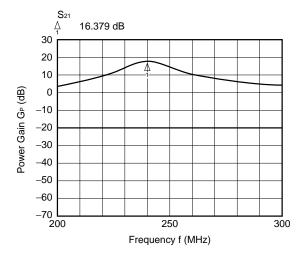
Conditions: TA = +25°C, Vcc = Vout = 3.0 V, ZL = Zs = 50 Ω

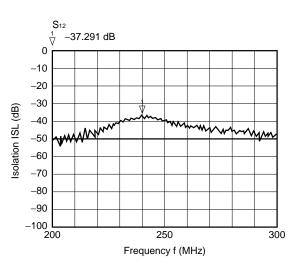




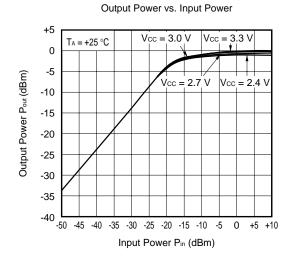


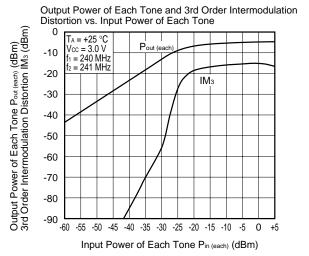


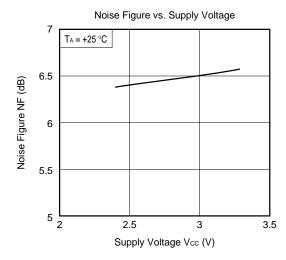




μ PC8151TB Characteristics for 240-MHz Tuning

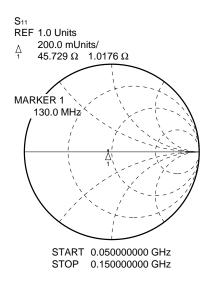


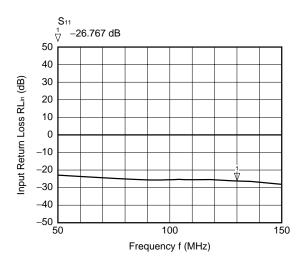


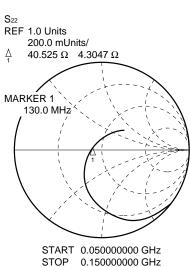


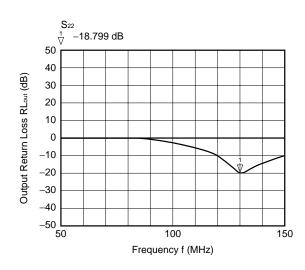
4.2.5 μPC8152TB Characteristics for 130-MHz Tuning

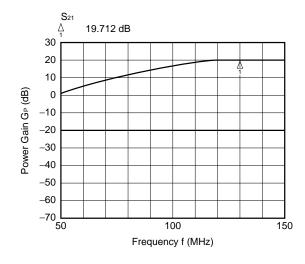
Conditions: TA = +25°C, Vcc = Vout = 3.0 V, ZL = Zs = 50 Ω

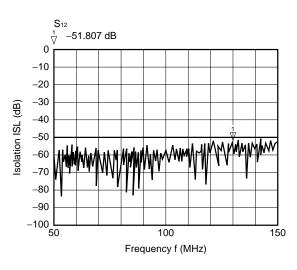




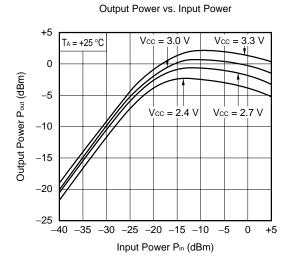


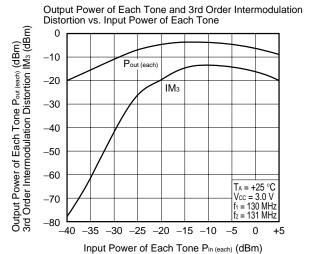


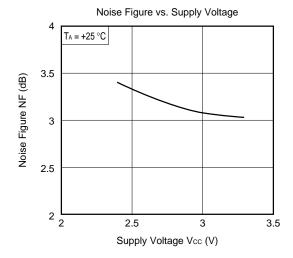




μ PC8152TB Characteristics for 130-MHz Tuning

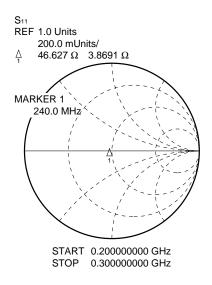


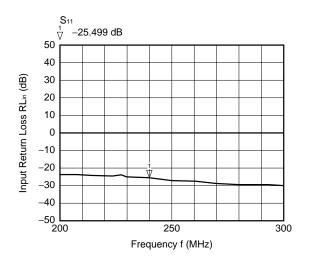


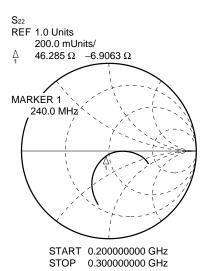


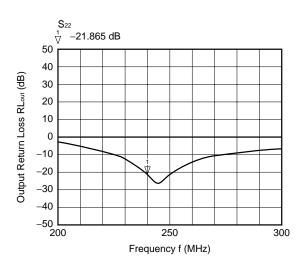
4.2.6 μPC8152TB Characteristics for 240-MHz Tuning

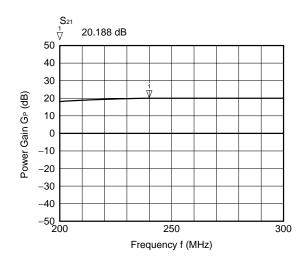
Conditions: TA = +25°C, Vcc = Vout = 3.0 V, ZL = Zs = 50 Ω

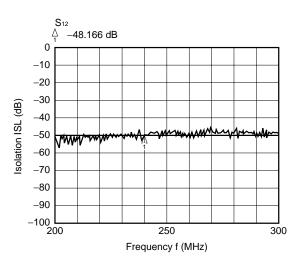




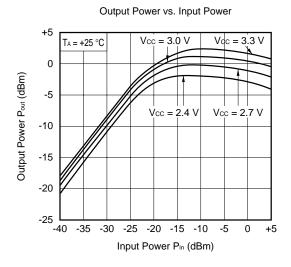


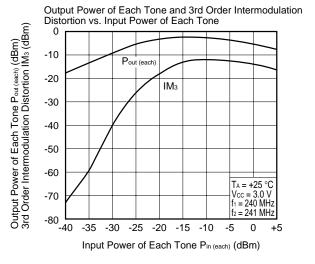






μ PC8152TB Characteristics for 240-MHz Tuning





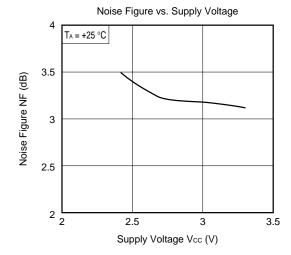
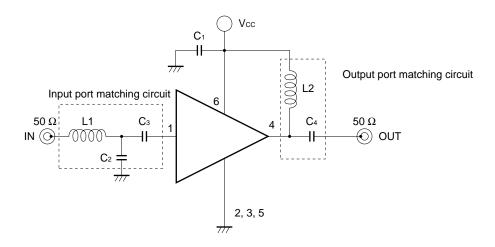


Figure 4-2. Test Circuits

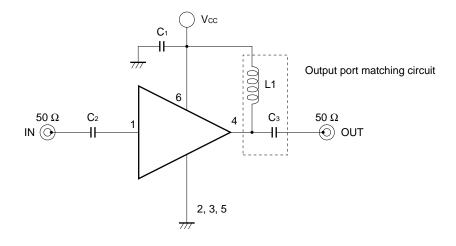
(1) μ PC8128TB/ μ PC8151TB



Component List

| - | 130-MHz Input/Output Tuning | 240-MHz Input/Output Tuning |
|----------------|-----------------------------|-----------------------------|
| C ₁ | 1 000 pF | 1 000 pF |
| C ₂ | 2.5 pF | 0.5 pF |
| Сз | 200 pF | 1 000 pF |
| C4 | 3.5 pF | 1.5 pF |
| L1 | 180 nH | 83 nH |
| L2 | 270 nH | 120 nH |

(2) μ PC8152TB



Component List

| | 130-MHz Input/Output Tuning | 240-MHz Input/Output Tuning | |
|---------------------------------|-----------------------------|-----------------------------|--|
| C ₁ , C ₂ | 1 000 pF | 1 000 pF | |
| Сз | 12 pF | 5 pF | |
| L1 | 135 nH | 68 nH | |

5. SUMMARY

Table 5-1. External Circuit Configuration and Characteristics

| External Circuit Configuration | Main Characteristic Change | Emphasized Characteristic |
|---|---|---|
| Output isolation matching (no matching for the input stage, and an output stage return loss optimized to approximately 10 to 20 dB) | Isolation and noise figure are better than for the output $50-\Omega$ matching and input/output $50-\Omega$ matching methods. | Isolation and noise figure are emphasized |
| Output 50-Ω matching (no matching for the input stage) | As compared with the output isolation matching method, power gain increases by approximately 1 dB. Isolation worsens by approximately 2 dB. | Power gain and noise figure are emphasized. |
| Input/output 50-Ω matching | As compared with the output isolation matching method, power gain increases by approximately 2 dB. Isolation worsens by approximately 3 dB. Noise figure worsens by approximately 1 dB. | Power gain is emphasized. |

6. CONCLUSION

These application notes explained the characteristics of application circuits using the μ PC8128TB, μ PC8151TB, and μ PC8152TB, which are a series of low-current silicon MMIC amplifiers for cellular/cordless telephones, and presented examples for selecting these ICs.

We hope that these application notes will be of some assistance to you when you use these silicon MMICs.

References

O Data sheets for each product μ PC8128TB, μ PC8151TB, μ PC8152TB (Document No. P12549E) μ PC2745TB, μ PC2746TB (Document No. P11511E) μ PC2747TB, μ PC2748TB (Document No. P13444E)

O Application Notes

Usage and Applications of 6-Pin Mini-mold, 6-Pin Super Mini-mold Silicon High-Frequency Wideband Amplifier MMIC (Document No. P11976E)

APPENDIX S PARAMETER REFERENCE VALUES (TA = +25°C)

 μ PC8128TB

Vcc = Vout = 3.0 V, Icc = 2.8 mA

| FREQUENCY | S | S ₁₁ | S | S ₂₁ | S | 12 | Sa | 22 |
|-----------|------|-------------------|-------|-----------------|------|-------|-------|-------|
| MHz | MAG | ANG | MAG | ANG | MAG | ANG | MAG | ANG |
| 400 0000 | 050 | 44.5 | 4.000 | 470.0 | 004 | 470.7 | 4.005 | 4.7 |
| 100.0000 | .859 | -14.5 | 1.089 | -176.0 | .001 | 176.7 | 1.005 | -1.7 |
| 200.0000 | .769 | -23.8 | 1.138 | -173.2 | .001 | 142.6 | 1.019 | -4.2 |
| 300.0000 | .694 | -27.1 | 1.208 | -171.0 | .003 | 112.3 | 1.015 | -5.8 |
| 400.0000 | .637 | -30.1 | 1.336 | -171.7 | .005 | 88.8 | .996 | -8.7 |
| 500.0000 | .595 | -32.4 | 1.478 | -172.8 | .005 | 77.7 | .976 | -10.9 |
| 600.0000 | .568 | -35.9 | 1.623 | -175.6 | .005 | 64.1 | .976 | -12.8 |
| 700.0000 | .555 | -40.7 | 1.822 | -179.0 | .006 | 73.7 | .983 | -14.1 |
| 800.0000 | .569 | -45.0 | 1.955 | 176.9 | .007 | 64.2 | .988 | -15.5 |
| 900.0000 | .597 | -49.4 | 2.147 | 172.5 | .007 | 72.5 | .973 | -17.4 |
| 1000.0000 | .633 | -52.6 | 2.307 | 166.8 | .008 | 49.9 | .945 | -19.9 |
| 1100.0000 | .643 | -56.3 | 2.468 | 160.6 | .008 | 66.8 | .928 | -22.0 |
| 1200.0000 | .644 | <i>–</i> 59.7 | 2.572 | 153.6 | .007 | 48.8 | .934 | -24.1 |
| 1300.0000 | .611 | -64.3 | 2.677 | 144.2 | .007 | 45.3 | .950 | -24.8 |
| 1400.0000 | .585 | -69.5 | 2.704 | 137.3 | .005 | 64.5 | .938 | -26.6 |
| 1500.0000 | .562 | - 75.1 | 2.693 | 128.8 | .005 | 66.0 | .913 | -28.2 |
| 1600.0000 | .559 | -80.5 | 2.712 | 122.7 | .005 | 93.6 | .898 | -30.1 |
| 1700.0000 | .547 | -85.4 | 2.640 | 116.3 | .006 | 83.5 | .892 | -32.0 |
| 1800.0000 | .540 | -89.5 | 2.665 | 110.4 | .005 | 101.6 | .893 | -33.6 |
| 1900.0000 | .524 | -93.2 | 2.599 | 104.5 | .005 | 115.4 | .896 | -34.7 |
| 2000.0000 | .503 | -97.8 | 2.582 | 98.5 | .006 | 110.9 | .895 | -36.5 |
| 2100.0000 | .474 | -103.5 | 2.500 | 93.1 | .007 | 129.4 | .877 | -38.6 |
| 2200.0000 | .461 | -110.0 | 2.472 | 86.7 | .008 | 130.5 | .873 | -40.4 |
| 2300.0000 | .465 | -116.2 | 2.453 | 80.9 | .009 | 137.8 | .878 | -41.9 |
| 2400.0000 | .475 | -121.0 | 2.426 | 74.8 | .010 | 133.3 | .877 | -43.5 |
| 2500.0000 | .488 | -123.1 | 2.364 | 70.4 | .012 | 139.0 | .871 | -45.4 |
| 2600.0000 | .491 | -125.0 | 2.310 | 63.9 | .011 | 140.8 | .864 | -47.9 |
| 2700.0000 | .480 | -125.1 | 2.282 | 61.1 | .014 | 142.6 | .855 | -51.1 |
| 2800.0000 | .460 | -127.0 | 2.159 | 56.3 | .014 | 140.7 | .851 | -53.0 |
| 2900.0000 | .437 | -129.4 | 2.205 | 51.4 | .016 | 141.5 | .867 | -55.1 |
| 3000.0000 | .410 | -133.4 | 2.085 | 48.8 | .018 | 143.2 | .861 | -57.0 |
| 3100.0000 | .401 | -137.8 | 2.038 | 42.4 | .019 | 142.1 | .855 | -60.0 |
| | | | | | | | | |

 μ PC8151TB Vcc = Vout = 3.0 V, Icc = 4.2 mA

| FREQUENCY | | S ₁₁ | 9 | S ₂₁ | S | 12 | S | 22 |
|-----------|------|-----------------|-------|------------------|------|--------------|-------|----------------|
| MHz | MAG | ANG | MAG | ANG | MAG | ANG | MAG | ANG |
| 100.0000 | .843 | -16.0 | 1.202 | -178.9 | .000 | 69.5 | .996 | -3.3 |
| 200.0000 | .752 | -10.0 -27.1 | 1.197 | -170.9 -177.5 | .003 | 120.2 | 1.009 | -6.9 |
| 300.0000 | .666 | -32.4 | 1.137 | -177.3 -175.4 | .003 | 103.2 | .998 | -9.9 |
| 400.0000 | .603 | -36.8 | 1.299 | -173.4 -174.5 | .003 | 92.8 | .986 | -13.8 |
| 500.0000 | .555 | -30.6 -40.5 | 1.398 | -174.0 | .004 | 88.8 | .968 | -13.0 -17.3 |
| 600.0000 | .528 | -44.8 | 1.513 | -174.0 -174.9 | .005 | 95.2 | .968 | -17.3 -20.4 |
| 700.0000 | .517 | -49.9 | 1.691 | -174.9 -176.2 | .003 | 67.5 | .971 | -23.1 |
| 800.0000 | .525 | -49.9 -54.4 | 1.815 | -176.2 -178.2 | .007 | 72.4 | .972 | -25.8 |
| 900.0000 | .545 | -54.4 -58.9 | 2.008 | 179.5 | .006 | 84.5 | .960 | -29.3 |
| 1000.0000 | .571 | -62.8 | 2.189 | 175.7 | .009 | 78.3 | .936 | -32.8 |
| 1100.0000 | .580 | -67.3 | 2.399 | 173.7 | .003 | 60.0 | .936 | -36.3 |
| 1200.0000 | .588 | -07.3 -71.3 | 2.560 | 165.9 | .007 | 89.5 | .920 | -30.5 -39.5 |
| 1300.0000 | .571 | -71.3 -76.4 | 2.736 | 157.5 | .007 | 67.2 | .933 | -39.3 -42.0 |
| 1400.0000 | .563 | -76.4 -82.3 | 2.736 | 151.3 | .008 | 79.6 | .930 | -42.0 -45.0 |
| 1500.0000 | .553 | -02.3 -88.8 | 2.946 | 143.3 | .006 | 79.0 79.9 | .930 | -45.0 -48.1 |
| | | | | | | | | |
| 1600.0000 | .552 | -95.2 | 3.077 | 137.0 | .006 | 91.4 | .895 | -51.5 |
| 1700.0000 | .551 | -101.5 | 3.083 | 130.1 | .009 | 102.3 | .888 | -54.8 |
| 1800.0000 | .550 | -107.5 | 3.174 | 123.9 | .009 | 100.5 | .884 | -57.3 |
| 1900.0000 | .536 | -113.3 | 3.164 | 117.4 | .006 | 109.5 | .885 | -60.2 |
| 2000.0000 | .517 | -119.8 | 3.193 | 110.7 | .009 | 115.9 | .881 | -63.4 |
| 2100.0000 | .495 | -127.1 | 3.149 | 104.4 | .010 | 124.2 | .870 | -66.6 |
| 2200.0000 | .484 | -135.3 | 3.143 | 97.3 | .011 | 122.4 | .867 | -69.8 |
| 2300.0000 | .484 | -142.6 | 3.135 | 90.5 | .012 | 131.7 | .866 | -72.3 |
| 2400.0000 | .490 | -148.5 | 3.120 | 83.5 | .015 | 138.1 | .868 | -75.5 |
| 2500.0000 | .499 | -152.5 | 3.053 | 78.4 | .016 | 136.3 | .866 | -78.7 |
| 2600.0000 | .499 | -155.8 | 2.991 | 71.4 | .018 | 142.9 | .864 | -82.5 |
| 2700.0000 | .485 | -157.4 | 2.958 | 68.0 | .018 | 143.9 | .858 | -86.6 |
| 2800.0000 | .464 | -160.6 | 2.810 | 62.9 | .021 | 142.5 | .852 | -89.7 |
| 2900.0000 | .439 | -164.1 | 2.866 | 57.5 | .022 | 149.3 | .872 | -93.4 |
| 3000.0000 | .416 | -168.6 | 2.713 | 54.5 | .025 | 148.4 | .864 | -96.6 |
| 3100.0000 | .403 | -173.6 | 2.635 | 48.0 | .030 | 143.6 | .867 | -101.0 |

 μ PC8152TB Vcc = Vout = 3.0 V, Icc = 5.6 mA

| FREQUENCY | S | 11 | S | 21 | S | 12 | S ₂ | 2 |
|----------------------|--------------|-------|----------------|-------------------|--------------|---------------|----------------|-------|
| MHz | MAG | ANG | MAG | ANG | MAG | ANG | MAG | ANG |
| 100,0000 | 060 | 168.0 | 6 601 | -0.3 | 002 | 40.8 | 775 | -3.3 |
| 100.0000 200.0000 | .062 .047 | 169.1 | 6.691 7.049 | -0.3 -3.7 | .002 .001 | 40.8 101.6 | .775 .773 | |
| | | | | | | | | -6.6 |
| 300.0000 | .055 | 166.9 | 7.418 | -9.3 | .003 | 97.3 | .761 | -9.1 |
| 400.0000 | .078 | 162.1 | 7.883 | -16.0 | .003 | 70.7 | .759 | -12.0 |
| 500.0000 | .101 | 155.6 | 8.311 | -22.1 | .005 | 76.7 | .754 | -15.3 |
| 600.0000 | .121 | 147.4 | 8.583 | -29.7 | .004 | 80.5 | .754 | -18.3 |
| 700.0000 | .135 | 141.2 | 9.093 | -37.3 | .006 | 79.8 | .756 | -21.3 |
| 800.0000 | .143 | 133.2 | 9.276 | -45.4 50.0 | .005 | 85.9 | .755 | -24.7 |
| 900.0000 | .146 | 122.4 | 9.572 | -53.6 | .009 | 89.6 | .752 | -28.1 |
| 1000.0000 | .146 | 108.9 | 9.763 | - 62.6 | .009 | 70.3 | .745 | -32.0 |
| 1100.0000 | .153 | 97.4 | 9.851 | -71.9 | .007 | 90.8 | .733 | -36.3 |
| 1200.0000 | .157 | 82.7 | 9.926 | -80.5 | .011 | 84.9 | .723 | -40.3 |
| 1300.0000 | .164 | 73.3 | 9.816 | -91.2 | .010 | 81.9 | .710 | -44.3 |
| 1400.0000 | .168 | 63.4 | 9.586 | -99.6 | .011 | 81.4 | .679 | -48.5 |
| 1500.0000 | .171 | 56.1 | 9.332 | -109.4 | .011 | 82.3 | .649 | -52.0 |
| 1600.0000 | .165 | 47.2 | 9.128 | -117.9 | .009 | 79.0 | .624 | -56.3 |
| 1700.0000 | .164 | 38.7 | 8.544 | -126.1 | .011 | 77.5 | .591 | -59.2 |
| 1800.0000 | .156 | 30.2 | 8.152 | -133.5 | .011 | 76.8 | .557 | -61.4 |
| 1900.0000 | .158 | 25.1 | 7.607 | -140.6 | .011 | 75.9 | .527 | -63.4 |
| 2000.0000 | .148 | 21.5 | 7.264 | -147.5 | .012 | 75.8 | .498 | -65.6 |
| 2100.0000 | .140 | 19.1 | 6.759 | -153.7 | .013 | 82.6 | .476 | -66.8 |
| 2200.0000 | .124 | 21.6 | 6.366 | -159.7 | .012 | 92.4 | .455 | -67.1 |
| 2300.0000 | .104 | 19.3 | 6.028 | -165.7 | .014 | 88.9 | .438 | -68.1 |
| 2400.0000 | .085 | 17.8 | 5.642 | -171.5 | .015 | 89.8 | .418 | -68.1 |
| 2500.0000 | .068 | 10.9 | 5.200 | -176.0 | .015 | 87.2 | .399 | -69.5 |
| 2600.0000 | .059 | 9.9 | 4.874 | 179.1 | .016 | 94.2 | .390 | -69.2 |
| 2700.0000 | .055 | -0.1 | 4.527 | 175.9 | .017 | 93.5 | .380 | -70.2 |
| 2800.0000 | .054 | 0.2 | 4.202 | 171.3 | .022 | 88.2 | .372 | -70.3 |
| 2900.0000 | .054 | 1.9 | 4.005 | 167.7 | .021 | 91.4 | .369 | -69.5 |
| 3000.0000 | .055 | 12.0 | 3.697 | 164.4 | .021 | 86.8 | .360 | -69.6 |
| 3100.0000 | .057 | 22.3 | 3.502 | 160.4 | .023 | 83.9 | .352 | -71.0 |
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